

FE	ATURES	DGG. D	GV. OR	DL PACKAGE
•	Member of the Texas Instruments Widebus™	,	(TOP \	
	Family		LТ	フーレ
٠	Operates From 1.65 V to 3.6 V	1 <del>0E</del>		48 2 <u>0E</u>
٠	Inputs Accept Voltages to 5.5 V		2	47 1A1
•	Max t <sub>pd</sub> of 4.1 ns at 3.3 V	1Y2		46   1A2 45   GND
•	Typical V <sub>OLP</sub> (Output Ground Bounce) <0.8 V	GND 1Y3		45 GND 44 1A3
	at $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$	113 1Y4		44 1 1A3 43 1A4
•	Typical V <sub>OHV</sub> (Output V <sub>OH</sub> Undershoot) >2 V	V <sub>CC</sub>		42 V <sub>CC</sub>
	at $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$	2Y1	-	41 2A1
•	I <sub>off</sub> Supports Partial-Power-Down Mode	2Y2		40 2A2
	Operation	GND		39 GND
•	Supports Mixed-Mode Signal Operation on All	2Y3	11	38 2A3
-	Ports (5-V Input/Output Voltage With	2Y4	12	37 🛛 2A4
	3.3-V V <sub>cc</sub> )	3Y1	13	36 🛛 3A1
•	Bus Hold on Data Inputs Eliminates the Need	3Y2	14	35 <b>3</b> A2
	for External Pullup/Pulldown Resistors	GND		34 🛛 GND
•	Latch-Up Performance Exceeds 250 mA Per	3Y3		33 <b>3</b> 3A3
•	JESD 17	3Y4		32 3A4
•	ESD Protection Exceeds JESD 22	V <sub>CC</sub>		31 V <sub>CC</sub>
•			19	30 4A1
	- 2000-V Human-Body Model (A114-A)	4Y2		29 4A2 28 GND
	– 200-V Machine Model (A115-A)	GND 4Y3		201 GND 27 4A3
	SCRIPTION/ORDERING INFORMATION	413 4Y4		26 4A3
		4 <u>0</u> E		25 3 <u>0E</u>
	is 16-bit buffer/driver is designed for 1.65-V to -V V <sub>CC</sub> operation.	ΨOL	۲	

The SN74LVCH16244A is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

T <sub>A</sub>	PACKA	GE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	FBGA – GRD			LDH244A
	FBGA – ZRD (Pb-free)	Tape and reel	SN74LVCH16244AZRDR	LDH244A
		Tube	SN74LVCH16244ADL	
	SSOP – DL	Tono and real	SN74LVCH16244ADLR	LVCH16244A
		Tape and reel	74LVCH16244ADLRG4	
–40°C to 85°C		Tono and real	SN74LVCH16244ADGGR	LVCH16244A
	TSSOP – DGG	Tape and reel	74LVCH16244ADGGRG4	
	TVSOP – DGV	Tono and roal	SN74LVCH16244ADGVR	LDH244A
	TVSOP - DGV	Tape and reel	74LVCH16244ADGVRE4	
	VFBGA – GQL	Tono and real	SN74LVCH16244AGQLR	LDH244A
	VFBGA – ZQL (Pb-free)	Tape and reel	SN74LVCH16244AZQLR	

#### **ORDERING INFORMATION**

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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SCES494A-OCTOBER 2003-REVISED NOVEMBER 2005

### **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. It provides true outputs and symmetrical active-low output-enable (OE) inputs.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

GQL OR ZQL PACKAGE (TOP VIEW)

	1 2 3 4 5 6
Α	000000
в	000000
С	0000000
D	000000
Е	00 00
F	00 00
G	000000
н	000000
J	000000
κ	000000

TERMINAL ASSIGNMENTS <sup>(1)</sup>
(56-Ball GQL/ZQL Package)

	1	2	3	4	5	6
Α	1 <mark>0E</mark>	NC	NC	NC	NC	2 <del>0E</del>
В	1Y2	1Y1	GND	GND	1A1	1A2
С	1Y4	1Y3	V <sub>CC</sub>	V <sub>CC</sub>	1A3	1A4
D	2Y2	2Y1	GND GND 2A1		2A2	
Ε	2Y4	2Y3			2A3	2A4
F	3Y1	3Y2			3A2	3A1
G	3Y3	3Y4	GND	GND	3A4	3A3
Н	4Y1	4Y2	V <sub>CC</sub>	V <sub>CC</sub>	4A2	4A1
J	4Y3	4Y4	GND	GND	4A4	4A3
Κ	4 <del>0E</del>	NC	NC	NC	NC	3 <mark>0E</mark>

(1) NC – No internal connection

#### TERMINAL ASSIGNMENTS<sup>(1)</sup> (54-Ball GRD/ZRD Package)

	1	2	3	4	5	6
Α	1Y1	NC	1 <del>0E</del>	2 <mark>0E</mark>	NC	1A1
В	1Y3	1Y2	NC	NC	1A2	1A3
С	2Y1	1Y4	V <sub>CC</sub>	V <sub>CC</sub>	1A4	2A1
D	2Y3	2Y2	GND	GND	2A2	2A3
Е	3Y1	2Y4	GND	GND	2A4	3A1
F	3Y3	3Y2	GND	GND	3A2	3A3
G	4Y1	3Y4	V <sub>CC</sub>	V <sub>CC</sub>	3A4	4A1
Н	4Y3	4Y2	NC	NC	4A2	4A3
J	4Y4	NC	4 <del>0E</del>	3 <mark>0E</mark>	NC	4A4

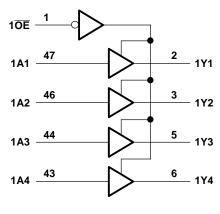
(1) NC - No internal connection

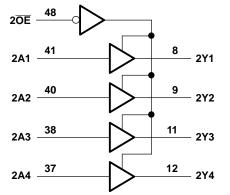
	GRD OR ZRD PACKAGE (TOP VIEW)								
		1	2	3	4	5	6	_	
A	$\left( \right)$		$\bigcirc$						
в		$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		
с		$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		
D		$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		
Е		$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		
F		$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		
G		$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		
н		$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		
J	l	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$		

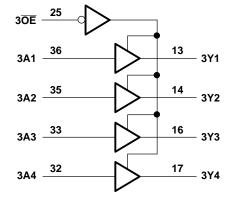
#### FUNCTION TABLE (EACH 4-BIT BUFFER)

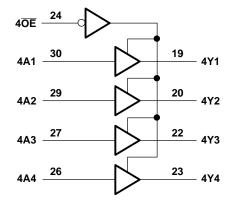
INPL	JTS	OUTPUT
ŌĒ	Α	Y
L	Н	Н
L	L	L
Н	Х	Z

### LOGIC DIAGRAM (POSITIVE LOGIC)









Pin numbers shown are for the DGG, DGV, and DL packages.

## SN74LVCH16244A 16-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCES494A-OCTOBER 2003-REVISED NOVEMBER 2005



#### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	range <sup>(2)</sup> applied to any output in the high-impedance or power-off state <sup>(2)</sup> applied to any output in the high or low state <sup>(2)(3)</sup> urrent $V_1 < 0$ current $V_0 < 0$ utput current   urrent     urrent through each V <sub>CC</sub> or GND   DGG package     DGV package   DGV package     DL package   DL package			
VI	Input voltage range <sup>(2)</sup>		-0.5	6.5	V
Vo	Voltage range applied to any output in the h	-0.5	6.5	V	
Vo	Voltage range applied to any output in the h	Voltage range applied to any output in the high or low state <sup>(2)(3)</sup>			
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>0</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current		±50	mA	
	Continuous current through each V <sub>CC</sub> or GN	ND		±100	mA
		DGG package		70	
		DGV package		58	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DL package		63	
		GQL/ZQL package		42	
		GRD/ZRD package		36	
T <sub>stg</sub>	Storage temperature range	·	-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of  $V_{CC}$  is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

### **Recommended Operating Conditions**<sup>(1)</sup>

			MIN	MAX	UNIT	
V	High-level input voltage Low-level input voltage Input voltage Output voltage High-level output current Low-level output current	Operating	1.65	3.6		
VCC		Data retention only	1.5		V	
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65  imes V_{CC}$			
V <sub>IH</sub>	High-level input voltage Low-level input voltage Input voltage Output voltage High-level output current Low-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
		V <sub>CC</sub> = 2.7 V to 3.6 V	$\begin{array}{c c c c c c c c c c c c c c c c c c c $			
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35  imes V_{CC}$		
V <sub>IL</sub>	Low-level input voltage	evel input voltage $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
	IH   High-level input voltage     IL   Low-level input voltage     I   Input voltage     O   Output voltage     OH   High-level output current     UL   Low-level output current     UL   Low-level output current     UL   Input transition rise or fall rate	V <sub>CC</sub> = 2.7 V to 3.6 V		0.8		
VI	Input voltage		0	5.5	V	
V.	Output usltage	High or low state	0	V <sub>CC</sub>	V	
vo	Input voltage Output voltage	3-state	0		v	
		V <sub>CC</sub> = 1.65 V		-4		
		V <sub>CC</sub> = 2.3 V		-8		
$V_{IH}$ High-level $V_{IL}$ Low-level $V_I$ Input vol $V_O$ Output v $I_{OH}$ High-level $I_{OL}$ Low-level $\Delta t/\Delta v$ Input training	High-level output current	V <sub>CC</sub> = 2.7 V		-12	mA	
		$V_{CC} = 3 V$		-24		
		V <sub>CC</sub> = 1.65 V		4		
		V <sub>CC</sub> = 2.3 V		8	mA	
OL	Low-level output current	output current $V_{CC} = 2.7 V$				
		V <sub>CC</sub> = 3 V		24	1	
$\Delta t/\Delta v$	Input transition rise or fall rate			10	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

 All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

SCES494A-OCTOBER 2003-REVISED NOVEMBER 2005

#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST C	ONDITIONS	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup> MAX	UNI	
	I <sub>OH</sub> = −100 μA		1.65 V to 3.6 V	$V_{CC} - 0.2$			
V <sub>OH</sub> V <sub>OL</sub> I <sub>I</sub> I <sub>I(hold)</sub> I <sub>off</sub> I <sub>OZ</sub> I <sub>CC</sub>	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2				
	I <sub>OH</sub> = -8 mA	2.3 V	1.7				
	10 m		2.7 V	2.2		V	
	I <sub>OH</sub> = -12 mA		3 V	2.4			
	I <sub>OH</sub> = -24 mA		3 V	2.2	$\begin{array}{c c} -0.2 \\ 1.2 \\ 1.7 \\ 2.2 \\ 2.4 \\ 2.2 \\ \hline 0.45 \\ 0.45 \\ \hline 0.7 \\ 0.45 \\ \hline 0.55 \\ \hline 15 \\ -15 \\ 45 \\ -45 \\ 75 \\ -75 \\ \hline -75 \\ \hline 10 \\ \pm 10 \\ \pm 10 \\ 10 \\ \pm 10 \\ 20 \\ \hline 20 \\ 5.5 \\ \hline \end{array}$		
	I <sub>OL</sub> = 100 μA		1.65 V to 3.6 V		0.2		
	$I_{OL} = 4 \text{ mA}$		1.65 V		0.45		
lı	I <sub>OL</sub> = 8 mA		2.3 V		0.7	V	
	I <sub>OL</sub> = 12 mA		2.7 V		0.4		
	$I_{OL} = 24 \text{ mA}$		3 V		0.55		
l <sub>l</sub>	$V_{I} = 0$ to 5.5 V		3.6 V		±5	μA	
	V <sub>I</sub> = 0.58 V	1.65.\/	15				
	V <sub>I</sub> = 1.07 V	1.65 V	-15				
	V <sub>I</sub> = 0.7 V	2.3 V	45				
I <sub>I(hold)</sub>	V <sub>I</sub> = 1.7 V		2.3 V	-45		μA	
	V <sub>I</sub> = 0.8 V		- 3 V	75			
	V <sub>1</sub> = 2 V	 	-75				
	$V_{I} = 0$ to 3.6 V <sup>(2)</sup>		3.6 V		±500		
I <sub>off</sub>	$V_{I} \text{ or } V_{O} = 5.5 \text{ V}$		0		±10	μA	
I <sub>OZ</sub>	$V_0 = 0$ to 5.5 V		3.6 V		±10	μA	
1	$V_{I} = V_{CC} \text{ or } GND$		261/		20		
ICC	$3.6 \text{ V} \le \text{V}_{\text{I}} \le 5.5 \text{ V}^{(3)}$	$I_{O} = 0$	3.6 V		20	μA	
$\Delta I_{CC}$	One input at $V_{CC} - 0.6 V$ ,	Other inputs at V <sub>CC</sub> or GND 2.7 V to 3.6 V			500	μA	
Ci	$V_{I} = V_{CC} \text{ or } GND$		3.3 V		5.5	pF	
Co	$V_0 = V_{CC}$ or GND		3.3 V		6	pF	

(1)

All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> =  $25^{\circ}$ C. This is the bus-hold maximum dynamic current required to switch the input from one state to another. This applies in the disabled state only. (2) (3)

#### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	_	FROM TO	V <sub>CC</sub> = ± 0.1	1.8 V 5 V	$V_{CC}$ = 2.5 V ± 0.2 V		$\begin{array}{c} V_{CC} = 2.5 \ V \\ \pm \ 0.2 \ V \end{array} \hspace{0.5cm} V_{CC} = 2.7 \end{array}$		2.7 V	.7 V V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
		(001601)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
t <sub>pd</sub>	А	Y	1.5	6.6	1	3.9	1	4.7	1.1	4.1	ns	
t <sub>en</sub>	OE	Y	1.5	7.5	1	4.7	1	5.8	1	4.6	ns	
t <sub>dis</sub>	OE	Y	1.5	10.3	1	5.3	1	6.2	1.8	5.8	ns	
t <sub>sk(o)</sub>										1	ns	

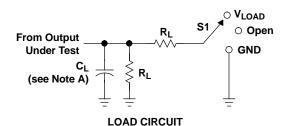
#### **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER			V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT
C	Power dissipation capacitance	Outputs enabled	f - 10 MHz	33	32	35	pF
C <sub>pd</sub>	per buffer/driver	Outputs disabled	f = 10 MHz	2	2	3	

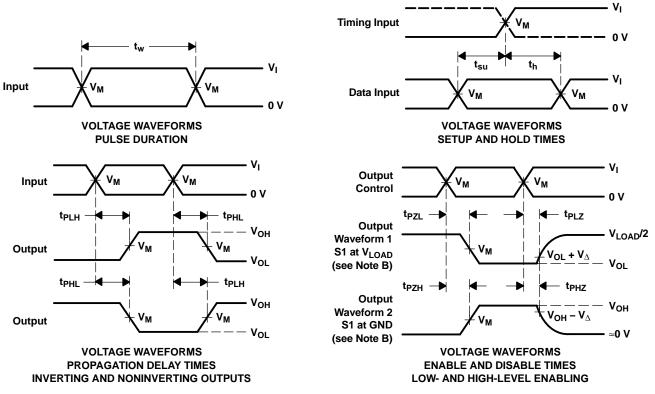
SCES494A-OCTOBER 2003-REVISED NOVEMBER 2005

#### PARAMETER MEASUREMENT INFORMATION



TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

	INPUTS				•	-	
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	VM	V <sub>LOAD</sub>	CL	RL	$V_\Delta$
1.8 V $\pm$ 0.15 V	v <sub>cc</sub>	≤2 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	30 pF	<b>500</b> Ω	0.15 V
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V
3.3 V $\pm$ 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V



NOTES: A. C<sub>1</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z\_O = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

#### Figure 1. Load Circuit and Voltage Waveforms



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3-Dec-2012

### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	•	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Samples
	(1)		Drawing			(2)		(3)	(Requires Login)
74LVCH16244ADGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
74LVCH16244ADGVRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
74LVCH16244ADGVRG4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
74LVCH16244ADLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCH16244ADGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCH16244ADGVR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCH16244ADL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCH16244ADLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCH16244ADLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SN74LVCH16244AGQLR	OBSOLETI	BGA MICROSTAR JUNIOR	GQL	56		TBD	Call TI	Call TI	
SN74LVCH16244AGRDR	OBSOLETI	BGA MICROSTAR JUNIOR	GRD	54		TBD	Call TI	Call TI	
SN74LVCH16244AZQLR	ACTIVE	BGA MICROSTAR JUNIOR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	
SN74LVCH16244AZRDR	ACTIVE	BGA MICROSTAR JUNIOR	ZRD	54	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.



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3-Dec-2012

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



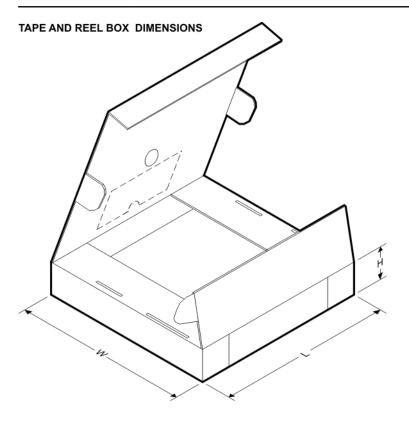
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVCH16244ADGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1
SN74LVCH16244ADGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74LVCH16244ADLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1
SN74LVCH16244AZQLR	BGA MI CROSTA R JUNI OR	ZQL	56	1000	330.0	16.4	4.8	7.3	1.5	8.0	16.0	Q1
SN74LVCH16244AZRDR	BGA MI CROSTA R JUNI OR	ZRD	54	1000	330.0	16.4	5.8	8.3	1.55	8.0	16.0	Q1

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# PACKAGE MATERIALS INFORMATION

10-Oct-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVCH16244ADGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74LVCH16244ADGVR	TVSOP	DGV	48	2000	367.0	367.0	38.0
SN74LVCH16244ADLR	SSOP	DL	48	1000	367.0	367.0	55.0
SN74LVCH16244AZQLR	BGA MICROSTAR JUNIOR	ZQL	56	1000	333.2	345.9	28.6
SN74LVCH16244AZRDR	BGA MICROSTAR JUNIOR	ZRD	54	1000	333.2	345.9	28.6

ZQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is Pb-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).

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GRD (R-PBGA-N54)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Falls within JEDEC MO-205 variation DD.

D. This package is tin-lead (SnPb). Refer to the 54 ZRD package (drawing 4204760) for lead-free.



ZRD (R-PBGA-N54)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Falls within JEDEC MO-205 variation DD.

D. This package is lead-free. Refer to the 54 GRD package (drawing 4204759) for tin-lead (SnPb).



GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



# **MECHANICAL DATA**

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

#### DGG (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE

**48 PINS SHOWN** 



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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